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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/705,223	11/12/2003	Yasuo Segawa	492322014700	3537
25227	7590 02/10/2006		EXAMINER	
	& FOERSTER LLP		QUINTO, KEVIN V	
SUITE 300	S BOULEVARD		ART UNIT	PAPER NUMBER
MCLEAN, V	A 22102		2826	

DATE MAILED: 02/10/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

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÷ ·		Application No.	Applicant(s)	- 00-			
Office Action Summary		10/705,223	SEGAWA ET AL.				
		Examiner	Art Unit				
		Kevin Quinto	2826				
Period fe	The MAILING DATE of this communication app or Reply	ears on the cover sheet with the	correspondence address				
WHI0 - Exte after - If NO - Fails Any	CORTENED STATUTORY PERIOD FOR REPLY CHEVER IS LONGER, FROM THE MAILING DAY INSTRUMENT OF A CFR 1.13 SIX (6) MONTHS from the mailing date of this communication. O period for reply is specified above, the maximum statutory period we are to reply within the set or extended period for reply will, by statute, reply received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATIO 36(a). In no event, however, may a reply be ti vill apply and will expire SIX (6) MONTHS fron cause the application to become ABANDONE	N. mely filed n the mailing date of this communicatio ED (35 U.S.C. § 133).	,			
Status							
1)⊠	Responsive to communication(s) filed on 18 No.	ovember 2005.					
2a)⊠	This action is FINAL . 2b) This action is non-final.						
3)□	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is						
	closed in accordance with the practice under E	x parte Quayle, 1935 C.D. 11, 4	53 O.G. 213.				
Disposit	ion of Claims						
4)⊠	4)⊠ Claim(s) <u>1 and 3-11</u> is/are pending in the application.						
,	4a) Of the above claim(s) is/are withdrawn from consideration.						
5)🖂	✓ Claim(s) 1 and 3-7 is/are allowed.						
6)⊠	Claim(s) <u>8,9 and 11</u> is/are rejected.						
7)🖂	☑ Claim(s) 10 is/are objected to.						
8)□	_						
Applicati	ion Papers						
9)	The specification is objected to by the Examiner	•					
	10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.						
,	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
	Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.05(a).						
11)	The oath or declaration is objected to by the Exa		-	• 7•			
Priority ι	ınder 35 U.S.C. § 119						
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No. 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). 							
Attachment	e of References Cited (PTO-892)	of the certified copies not received 4) Interview Summary					
2) Notice	e of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail Da	ate				
が Inform Paper	nation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) No(s)/Mail Date <u>20 October 2005</u> .	5) Notice of Informal P 6) Other:	atent Application (PTO-152)				

Application/Control Number: 10/705,223 Page 2

Art Unit: 2826

DETAILED ACTION

Response to Arguments

- 1. Applicant's arguments with respect to claims 8, 9, and 11 have been considered but are most in view of the new ground(s) of rejection.
- 2. The examiner notes newly amended claim 8 and therefore withdraws the rejection of claims 8-11 under 35 USC § 112, second paragraph.

Claim Rejections - 35 USC § 102

3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 4. Claims 8, 9, and 11 are rejected under 35 U.S.C. 102(e) as being anticipated by Hamada et al. (USPN 6,599,782 B2).
- 5. In reference to claim 8, Hamada et al. (USPN 6,599,782 B2, hereinafter referred to as the "Hamada" reference) discloses a manufacturing method which meets the claim. Figures 7A-10 illustrate a manufacturing method of a semiconductor device which comprises providing a substrate (301). A first semiconductor portion (350) and a second semiconductor portion (351) are formed on the substrate (301). An insulating

Application/Control Number: 10/705,223 Page 3

Art Unit: 2826

film (308) is provided on the first semiconductor portion (350) and the second semiconductor portion (351). A gate electrode (313) is formed on the insulating film (308) so that the gate electrode (313) and the first semiconductor portion (350) are part of a thin film transistor. A storage capacitor electrode (314) is formed on the insulating film (308) so that the storage capacitor electrode (314) and the second semiconductor portion (351) are part of a storage capacitor. Source and drain regions (316) are formed in the first semiconductor portion (350). A wiring (345) is formed which connects the first semiconductor portion (350) and the second semiconductor portion (351); this is understood to be a metal wiring (column 7, lines 30-34, column 15, lines 48-51).

- 6. In reference to claim 9, an interlayer insulating film (337 or 338 or 339) is formed over the first (350) and second (351) semiconductor portions. A first contact hole is formed in the interlayer insulating film (337 or 338 or 339) in order to provide contact with the first semiconductor portion (350). A second contact hole is formed in the interlayer insulating film (337 or 338 or 339) in order to provide contact with the second semiconductor portion (351).
- 7. In reference to claim 11, the source and drain regions (316) are formed by ion implantation (column 14, lines 60-63).

Allowable Subject Matter

8. Claims 1 and 3-7 were allowed in a previous Office action.

9. Claim 10 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

10. The following is a statement of reasons for the indication of allowable subject matter: the examiner is unaware of any prior art which suggest or renders obvious a fabrication method for a semiconductor device which has a thin film transistor and a capacitor constructed such that the thin film transistor and the capacitor each have a component made of semiconductor film, these films being two spaced apart bodies, formed on a substrate such that these films are electrically coupled together by a metal wiring which itself is connected to a pixel electrode.

Conclusion

11. Applicant's submission of an information disclosure statement under 37 CFR 1.97(c) with the fee set forth in 37 CFR 1.17(p) on October 20, 2005 prompted the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS**MADE FINAL. See MPEP § 609.04(b). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any

Art Unit: 2826

extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Kevin Quinto whose telephone number 151(574) 2721 CAMINER 1920. The examiner can normally be reached on M-F 8AM-5PM. TECHNOLOGY CENTER 2800

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan Flynn can be reached on (571) 272-1915. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).